TOSHIBA Power Transistor Module Silicon NPN Epitaxial Type (Fourd Darlington Power tTransistors in One)

MP4020

High Power Switching Applications Hammer Drive, Pulse Motor Drive and Inductive Load Switching

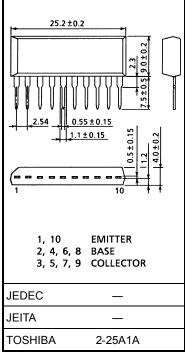
- Small package by full molding (SIP 10 pins)
- High collector power dissipation (4-device operation)
 PT = 4 W (Ta = 25°C)
- High collector current: $I_{C(DC)} = 2 A (max)$
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2$ V, $I_{C} = 1$ A)
- · Zener diode included between collector and base

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	50	V	
Collector-emitter voltage		V _{CEO}	60 ± 10	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	Ic	2	А	
	Pulse	I _{CP}	3		
Continuous base current		Ι _Β	0.5	Α	
Collector power dissipation (1 device operation)		PC	2.0	W	
Collector power dissipation (4 devices operation)		P _T	4.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

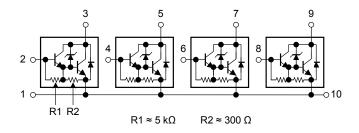
Industrial Applications

Unit: mm



Weight: 2.1 g (typ.)

Array Configuration





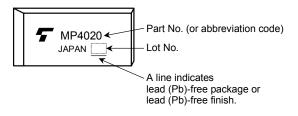
Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient (4-devices operation, Ta = 25°C)	ΣR _{th (j-a)}	31.3	°C/W	
Maximum lead temperature for soldering purposes (3.2 mm from case for 10 s)	TL	260	°C	

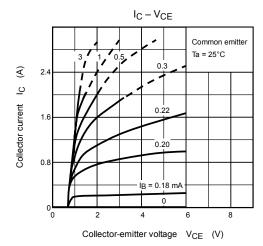
Electrical Characteristics (Ta = 25°C)

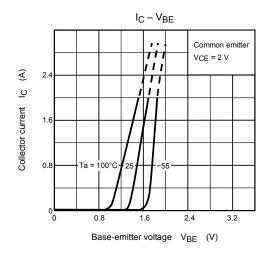
Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 45 V, I _E = 0 A	_	_	10	μA
Collector cut-off current		I _{CEO}	V _{CE} = 45 V, I _B = 0 A	_	_	10	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0 A	0.8	_	4.0	mA
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0 A	50	60	70	V
DC current gain		h _{FE}	V _{CE} = 2 V, I _C = 1 A	2000	_	_	_
Saturation voltage	Collector-emitter	V _{CE (sat)}	I _C = 1 A, I _B = 1 mA	_	_	1.5	V
	Base-emitter	V _{BE (sat)}	I _C = 1 A, I _B = 1 mA	_	_	2.0	
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	_	20	_	pF
Switching time	Turn-on time	t _{on}	Output Input B1 20 µs IB2 VCC = 30 V	_	0.4	_	μs
	Storage time	t _{stg}		_	4.0	_	
	Fall time	t _f		_	0.6	_	

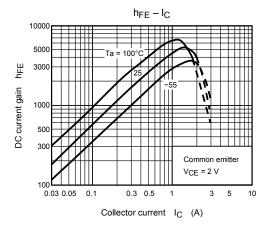
Marking

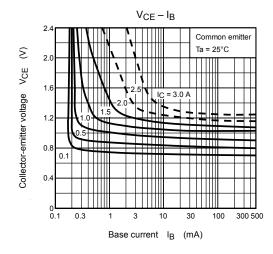


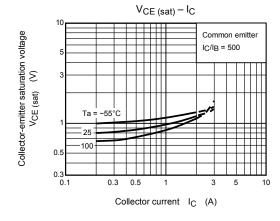
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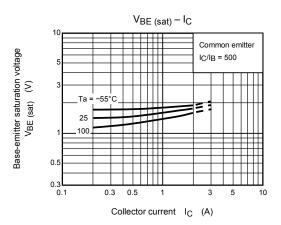


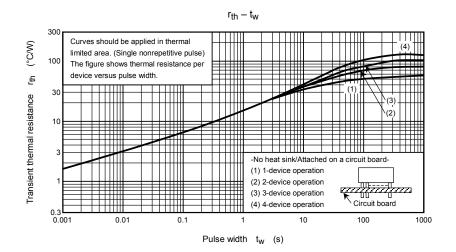


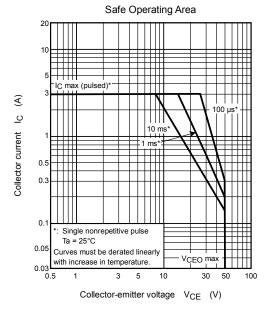


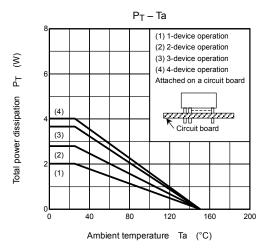


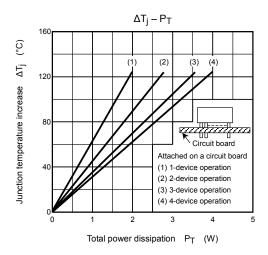












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